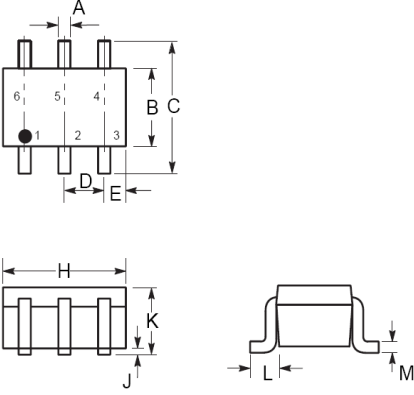


<b>SURFACE MOUNT FAST SWITCHING DIODE</b>	<b>REVERSE VOLTAGE – 75 Volts FORWARD CURRENT – 0.15 Ampere</b>
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<p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>• Fast switching speed</li> <li>• Ideally suited for automatic insertion</li> <li>• For general purpose switching applications</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>• Case: SOT-363 Plastic</li> <li>• Case material: “Green” molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)</li> <li>• Moisture sensitivity: Level 1 per J-STD-020D</li> <li>• Lead free in RoHS 2002/95/EC compliant</li> </ul>
---

**SOT-363**



SOT-363		
Dim.	Min.	Max.
A	0.15	0.35
B	1.15	1.35
C	2.15	2.45
D	0.65 TYP.	
E	0.40 REF.	
H	2.00	2.20
J	0.00	0.10
K	0.90	1.10
L	0.525 REF.	
M	0.08	0.15
Dimensions in millimeter		

**Maximum Ratings & Thermal Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified**

Characteristic	Symbol	BAW567DW	Units
Repetitive Peak Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>R</sub> RM V <sub>R</sub> WM V <sub>R</sub>	75	V
Forward Continuous Current	I <sub>F</sub> FM	300	mA
Average Rectified Output Current	I <sub>O</sub>	150	mA
Non-Repetitive Peak Forward Surge Current	I <sub>F</sub> SM	2 1	A
Power Dissipation	P <sub>D</sub>	200	mW
Thermal Resistance Junction to Ambient	R <sub>θ</sub> JA	625	°C/W
Operating Temperature Range	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-65~+150	°C

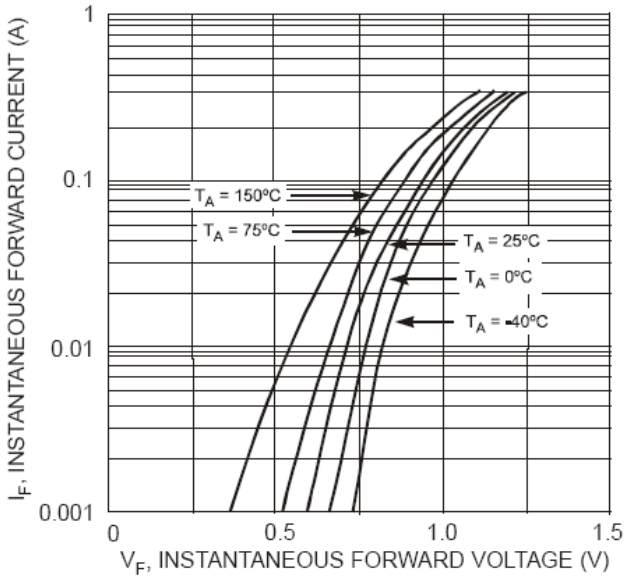
**Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified**

Characteristic	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	I <sub>R</sub> = 2.5uA	V <sub>BR</sub>	75	--	--	V
Maximum Forward Voltage	I <sub>F</sub> = 1mA	V <sub>F</sub>	--	--	715	mV
	I <sub>F</sub> = 10mA		--	--	855	
	I <sub>F</sub> = 50mA		--	--	1000	
	I <sub>F</sub> = 150mA		--	--	1250	
Maximum DC Reverse Current at Rated DC Blocking Voltage	V <sub>R</sub> = 75V V <sub>R</sub> = 20V	I <sub>R</sub>	--	--	2.5 0.025	uA
Typical Diode Capacitance	V <sub>R</sub> = 0V, f=1MHz	C <sub>D</sub>	--	--	2	pF

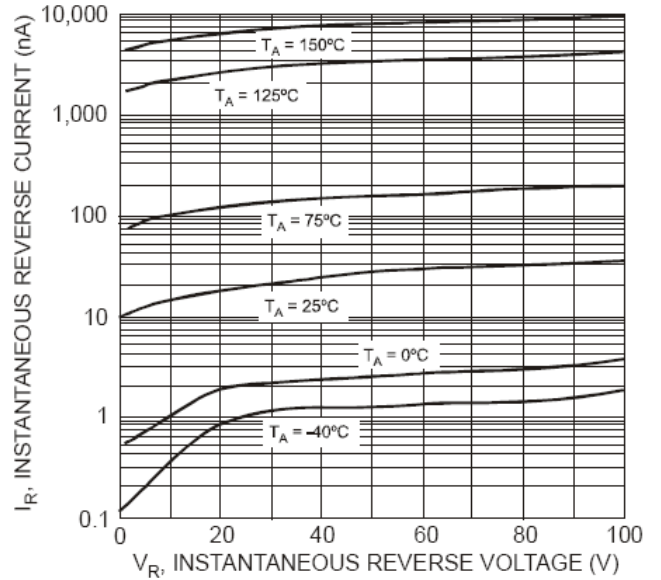
# RATING AND CHARACTERISTIC CURVES BAW567DW



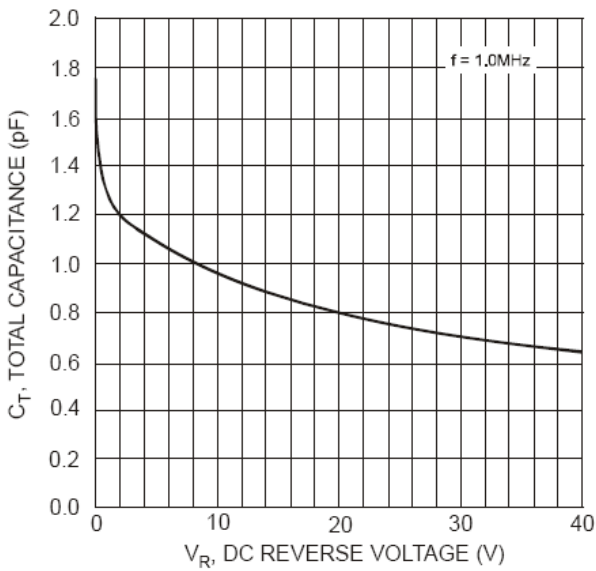
**Fig.1 Typical Forward Characteristics**



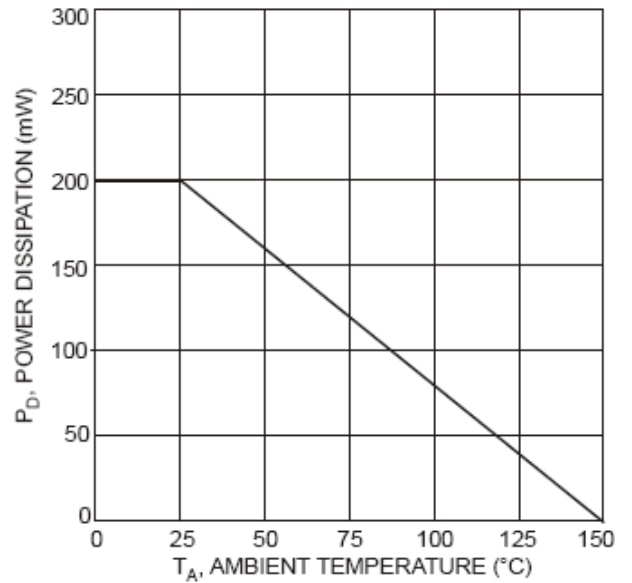
**Fig.2 Typical Reverse Characteristics**



**Fig.3 Total Capacitance vs. Reverse Voltage**



**Fig.4 Power Derating Curve**



**Device Marking :**

Device P/N	Marking code	Equivalent Circuit Diagram
BAW567DW	KAC	<p>The equivalent circuit diagram shows a 3-terminal device with pins 1, 2, 3, 4, 5, and 6. It consists of three diodes connected in parallel between pins 1 and 2, pins 2 and 3, and pins 3 and 4. Pin 5 is connected to pin 6, and pin 4 is connected to pin 5.</p>

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